













SN74LVC1G06

SCES295X -JUNE 2000-REVISED AUGUST 2015

SN74LVC1G06 Single Inverter Buffer/Driver With Open-Drain Output

Features

- Available in the Texas Instruments NanoFree™ Package
- Supports 5-V V_{CC} Operation
- Input and Open-Drain Output Accept Voltages up to 5.5 V
- Maximum t_{pd} of 4.5 ns at 3.3 V at 125°C
- Low Power Consumption, 10-µA Maximum I_{CC}
- ±24-mA Output Drive at 3.3 V for open-drain devices
- I_{off} Supports Live Insertion, Partial-Power-Down Mode, and Back-Drive Protection
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- Can Be Used For Up or Down Translation
- Schmitt Trigger Action on All Ports
- ESD Protection Exceeds JESD 22
 - 2000-V Human Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

2 Applications

- **AV Receivers**
- Blu-ray Players and Home Theaters
- **DVD Recorders and Players**
- Desktop or Notebook PCs
- Digital Radio or Internet Radio Players
- Digital Video Cameras (DVC)
- **Embedded PCs**
- **GPS: Personal Navigation Devices**
- Mobile Internet Devices
- **Network Projector Front-Ends**
- Portable Media Players
- Pro Audio Mixers
- **Smoke Detectors**
- Solid State Drive (SSD): Enterprise
- High-Definition (HDTV)
- Tablets: Enterprise
- Audio Docks: Portable
- **DLP Front Projection Systems**
- DVR and DVS
- Digital Picture Frame (DPF)
- Digital Still Cameras

3 Description

This single inverter buffer and driver is designed for 1.65-V to 5.5-V V_{CC} operation.

NanoFree package technology is breakthrough in IC packaging concepts, using the die as the package.

The output of the SN74LVC1G06 device is opendrain and can be connected to other open-drain outputs to implement active-low wired-OR or activehigh wired-AND functions. The maximum sink current is 32 mA.

This device is fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

Device Information

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
	SOT-23 (5)	2.90 mm × 1.60 mm		
	SC70 (5)	2.00 mm x 1.25 mm		
	SOT (5)	1.60 mm × 1.20 mm		
SN74LVC1G06	USON (6)	1.45 mm × 1.00 mm		
	X2SON (6)	1.00 mm x 1.00 mm		
	20201 (2)	1.40 mm × 0.90 mm		
	DSBGA (5)	0.90 mm × 0.90 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Logic Diagram (Positive Logic)

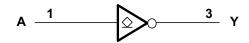




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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision W (December 2013) to Revision X

Page

Added Device Information table, Pin Configuration and Functions section, ESD Ratings table, Thermal Information table, Typical Characteristics section, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section

Changes from Revision V (November 2012) to Revision W

Page

Updated document to new TI data sheet format.
 Removed Ordering Information table.
 Updated I_{off} in Features.

Updated operating temperature range. 6

Submit Documentation Feedback

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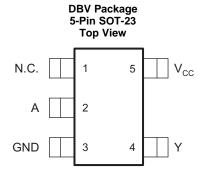
5 Device Comparison Table

PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74LVC1G06DBV	SOT-23 (5)	2.90 mm × 1.60 mm
SN74LVC1G06DCK	SC70 (5)	2.00 mm × 1.25 mm
SN74LVC1G06DRL	SOT (5)	1.60 mm × 1.20 mm
SN74LVC1G06DRY	USON (6)	1.45 mm × 1.00 mm
SN74LVC1G06DSF	X2SON (6)	1.00 mm x 1.00 mm
SN74LVC1G06YZP	DSBGA (5)	1.40 mm × 0.90 mm
SN74LVC1G06YZV	DSBGA (4)	0.90 mm × 0.90 mm

Product Folder Links: SN74LVC1G06

TEXAS INSTRUMENTS

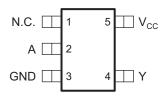
6 Pin Configuration and Functions



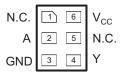




DCK Package 5-Pin SC70 Top View



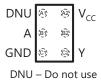
DRY Package 5-Pin USON Top View



DSF Package 5-Pin X2SON Top View



YZP Package 6-Pin DSGBA Top View



YZV Package 4-Pin DSBGA Top View



Pin Functions (1)(2)

		PIN				
NAME	DBV, DCK, DRL	DRY, DSF	YZP	YZV	1/0	DESCRIPTION
NC	1	1, 5	A1, B2	-	_	Not connected
Α	2	2	B1	A1	1	Input
GND	3	3	C1	B1	_	Ground
Υ	4	4	C2	B2	0	Output
V _{CC}	5	6	A2	A2	_	Power pin

Product Folder Links: SN74LVC1G06

(1) N.C. – No internal connection

(2) See mechanical drawings for dimensions



7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		-0.5	6.5	V
VI	Input voltage (2)		-0.5	6.5	V
Vo	Voltage applied to any output in the high-impedance or power	er-off state ⁽²⁾	-0.5	6.5	V
Vo	Voltage applied to any output in the high or low state (2)(3)	any output in the high or low state (2)(3)		6.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through V _{CC} or GND			±100	mA
Tj	Junction temperature		-65	150	°C
T _{stg}	Storage temperature		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
V	Floatroctatio discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	+2000	V
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	+1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

Product Folder Links: SN74LVC1G06

⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The value of V_{CC} is provided in the *Recommended Operating Conditions* table.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT			
.,	Cumply voltage	Operating	1.65	5.5	V			
V_{CC}	Supply voltage	Data retention only	1.5		V			
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	0.65 × V _{CC}					
V	High lovel input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V			
V_{IH}	High-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$	2		V			
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	$0.7 \times V_{CC}$					
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$				
V	Low level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V			
V_{IL}	Low-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$		0.8	V			
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		$0.3 \times V_{CC}$				
V_{I}	Input voltage	·	0	5.5	V			
Vo	Output voltage		0	5.5	V			
		V _{CC} = 1.65 V		4				
		$V_{CC} = 2.3 \text{ V}$		8				
I_{OL}	Low-level output current	V _{CC} = 3 V		16	mA			
		∧CC = 2 ∧		24				
		$V_{CC} = 4.5 V$		32				
		$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}, 2.5 \text{ V} \pm 0.2 \text{ V}$		20				
$\Delta t/\Delta v$	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V			
		$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$		5				
T_A	Operating free-air temperature		-40	125	°C			

All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.

7.4 Thermal Information

				SI	N74LVC1G0	6			IINIT	
	THERMAL METRIC ⁽¹⁾		DCK (SC70)	DRL (SOT)	DRY (USON)	YZP (DSBGA)	DSF (X2SON)	YZV (DSBGA)	UNIT	
		5 PINS	5 PINS	5 PINS	6 PINS	5 PINS	6 PINS	4 PINS		
Re	Junction-to-ambient thermal resistance	206	252	142	234	132	300	123	°C/W	

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAI	METER	TEST CONDITIONS	V _{CC}	MIN TYP ⁽¹⁾	MAX	UNIT
		I _{OL} = 100 μA	1.65 V to 5.5 V		0.1	
V _{OL}		I _{OL} = 4 mA	1.65 V		0.45	
		I _{OL} = 8 mA	2.3 V		0.3	\/
		I _{OL} = 16 mA	3 V		0.4	V
		I _{OL} = 24 mA	3 V		0.55	
		I _{OL} = 32 mA	4.5 V		0.55	
I	A input	V _I = 5.5 V or GND	0 to 5.5 V		±1	μΑ
I _{off}		V_I or $V_O = 5.5 \text{ V}$	0		±10	μΑ
Icc		$V_{I} = 5.5 \text{ V or GND}, I_{O} = 0$	1.65 V to 5.5 V		10	μΑ
ΔI _{CC}		One input at $V_{CC} - 0.6 \text{ V}$, Other inputs at V_{CC} or GND	3 V to 5.5 V		500	μΑ

(1) All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



Electrical Characteristics (continued)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}	MIN TY	P ⁽¹⁾ MAX	UNIT
C _i	$V_I = V_{CC}$ or GND	3.3 V		4	pF
Co	$V_O = V_{CC}$ or GND	3.3 V		5	pF

7.6 Switching Characteristics, -40°C to 85°C

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = ± 0.1		V _{CC} = ± 0.2		V _{CC} = ± 0.3		V _{CC} = ± 0.5		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _{pd}	А	Υ	2.2	6.5	1.1	4	1.2	4	1	3	ns

7.7 Switching Characteristics, -40°C to 125°C

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM	TO (OUTPUT)	V _{CC} = ± 0.1		V _{CC} = ± 0.2		V _{CC} = 0.3		V _{CC} = ± 0.5		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	Α	Υ	2.2	7	1.1	4.5	1.2	4.5	1	3.5	ns

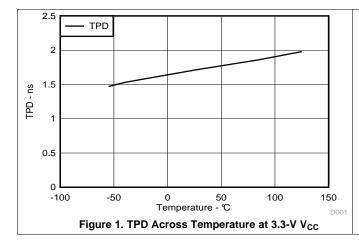
7.8 Operating Characteristics

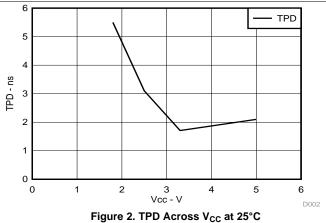
 $T_A = 25^{\circ}C$

	DADAMETED	TEST CONDITIONS	V _{CC} = 1.8 V	V _{CC} = 2.5 V	V _{CC} = 3.3 V	V _{CC} = 5 V	UNIT	
PARAMETER		TEST CONDITIONS	TYP	TYP	TYP	TYP	UNII	
C_{pd}	Power dissipation capacitance	f = 10 MHz	3	3	4	6	pF	

Product Folder Links: SN74LVC1G06

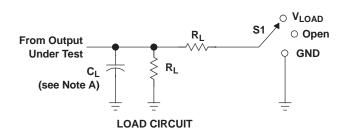
7.9 Typical Characteristics





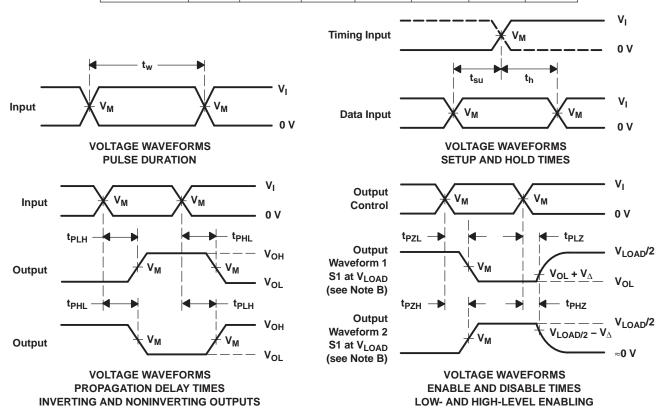


8 Parameter Measurement Information



TEST	S 1
t _{PZL} (see Notes E and F)	V_{LOAD}
t _{PLZ} (see Notes E and G)	V_{LOAD}
t _{PHZ} /t _{PZH}	V_{LOAD}

	INPUT				_		
V _{CC}	VI	t _r /t _f	V _M	V _{LOAD}	CL	R _L	V_{Δ}
1.8 V ± 0.15 V	V _{CC}	≤ 2 ns	V _{CC} /2	2×V _{CC}	30 pF	1 k Ω	0.15 V
2.5 V \pm 0.2 V	V _{CC}	≤ 2 ns	V _{CC} /2	2 × V _{CC}	30 pF	500 Ω	0.15 V
3.3 V \pm 0.3 V	3 V	≤ 2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5 V \pm 0.5 V	V _{CC}	≤ 2.5 ns	V _{CC} /2	$2 \times V_{CC}$	50 pF	500 Ω	0.3 V



- NOTES: A. C_I includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50~\Omega$.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. Since this device has open-drain outputs, t_{PLZ} and t_{PZL} are the same as t_{pd} .
 - F. t_{PZL} is measured at V_{M} .
 - G. t_{PLZ} is measured at $V_{OL} + V_{\Delta}$.
 - H. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms (Open Drain)



9 Detailed Description

9.1 Overview

The SN74LVC1G06 device contains one open-drain inverter with a maximum sink current of 32 mA. This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

9.2 Functional Block Diagram



9.3 Feature Description

The wide operating voltage range of 1.65 V to 5.5 V allows the SN74LVC1G06 to be used in systems with many different voltage rails. In addition, the voltage tolerance on the output allows the device to be used for inverting up-translation or down-translation. The I_{OFF} feature safely allows voltage on the inputs and outputs when no V_{CC} is present.

9.4 Device Functional Modes

Table 1 lists the functional modes of the SN74LVC1G06.

Table 1. Function Table

INPUT A	OUTPUT Y
L	Hi-Z
Н	L

Product Folder Links: SN74LVC1G06



10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The SN74LVC1G06 is a high-drive CMOS device that can be used to implement a high output drive buffer, such as an LED application. It can sink 32 mA of current at 4.5 V making it ideal for high-drive applications. It is good for high-speed applications up to 100 MHz. The inputs are 5.5-V tolerant allowing it to translate up or down to V_{CC} . Below shows a simple LED driver application for a single channel of the device.

10.2 Typical Application

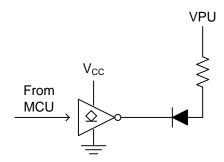


Figure 4. Typical Application Diagram

10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

10.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - Rise time and fall time specs. See (Δt/ΔV) in the Recommended Operating Conditions table.
 - Specified high and low levels. See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as (V_I max) in the Recommended Operating
 Conditions table at any valid V_{CC}.
- 2. Recommend Output Conditions
 - Load currents should not exceed (I_O max) per output and should not exceed (Continuous current through V_{CC} or GND) total current for the part. These limits are located in the *Absolute Maximum Ratings* table.
 - Outputs should not be pulled above 5.5 V.



Typical Application (continued)

10.2.3 Application Curve

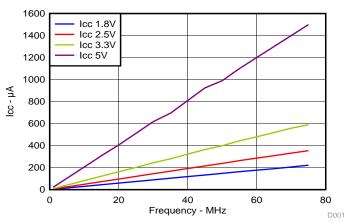


Figure 5. I_{CC} vs Frequency

Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the Recommended Operating Conditions table.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1- μ F capacitor is recommended and if there are multiple V_{CC} pins then a 0.01- μ F or 0.022- μ F capacitor is recommended for each power pin. It is ok to parallel multiple bypass caps to reject different frequencies of noise. 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

12 Layout

12.1 Layout Guidelines

When using multiple bit logic devices inputs must not ever float. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} whichever make more sense or is more convenient.

12.2 Layout Example

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Figure 6. Layout Diagram

Product Folder Links: SN74LVC1G06



13 Device and Documentation Support

13.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

13.2 Trademarks

NanoFree, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

13.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.

Product Folder Links: SN74LVC1G06





31-Jan-2016

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC1G06DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	(C065 ~ C06F ~ C06R ~ C06T) (C06H ~ C06P ~ C06S)	Samples
SN74LVC1G06DBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C06F	Samples
SN74LVC1G06DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C06F	Samples
SN74LVC1G06DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	(C065 ~ C06F ~ C06R) (C06H ~ C06P ~ C06S)	Samples
SN74LVC1G06DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C06F	Samples
SN74LVC1G06DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CT5 ~ CTF ~ CTK ~ CTR ~ CTT) (CTH ~ CTS)	Samples
SN74LVC1G06DCKRE4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CT5 ~ CTF ~ CTK ~ CTR ~ CTT) (CTH ~ CTS)	Samples
SN74LVC1G06DCKRG4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CT5 ~ CTF ~ CTK ~ CTR ~ CTT) (CTH ~ CTS)	Samples
SN74LVC1G06DCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CT5 ~ CTF ~ CTK ~ CTR) (CTH ~ CTS)	Samples
SN74LVC1G06DCKTE4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CT5 ~ CTF ~ CTK ~ CTR) (CTH ~ CTS)	Samples
SN74LVC1G06DCKTG4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CT5 ~ CTF ~ CTK ~ CTR) (CTH ~ CTS)	Samples
SN74LVC1G06DRLR	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CT7 ~ CTR)	Samples
SN74LVC1G06DRY2	PREVIEW	SON	DRY	6		TBD	Call TI	Call TI	-40 to 125	CT	



PACKAGE OPTION ADDENDUM

31-Jan-2016

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC1G06DRYR	ACTIVE	SON	DRY	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	CT	Samples
SN74LVC1G06DSF2	PREVIEW	SON	DSF	6		TBD	Call TI	Call TI	-40 to 125	CT	
SN74LVC1G06DSFR	ACTIVE	SON	DSF	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	СТ	Samples
SN74LVC1G06YZPR	ACTIVE	DSBGA	YZP	5	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(CT7 ~ CTN)	Samples
SN74LVC1G06YZVR	ACTIVE	DSBGA	YZV	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	CT (7 ~ N)	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

31-Jan-2016

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OTHER QUALIFIED VERSIONS OF SN74LVC1G06:

● Enhanced Product: SN74LVC1G06-EP

NOTE: Qualified Version Definitions:

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

www.ti.com 18-Jan-2016

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
D1	Pitch between successive cavity centers

- Reel Width (W1)

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G06DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G06DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G06DBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G06DBVT	SOT-23	DBV	5	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G06DBVTG4	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G06DCKR	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G06DCKT	SC70	DCK	5	250	180.0	9.2	2.3	2.55	1.2	4.0	8.0	Q3
SN74LVC1G06DCKT	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G06DRLR	SOT	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
SN74LVC1G06DRLR	SOT	DRL	5	4000	180.0	9.5	1.78	1.78	0.69	4.0	8.0	Q3
SN74LVC1G06DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74LVC1G06DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
SN74LVC1G06YZPR	DSBGA	YZP	5	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1
SN74LVC1G06YZVR	DSBGA	YZV	4	3000	178.0	9.2	1.0	1.0	0.63	4.0	8.0	Q1

PACKAGE MATERIALS INFORMATION

www.ti.com 18-Jan-2016



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G06DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0
SN74LVC1G06DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74LVC1G06DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74LVC1G06DBVT	SOT-23	DBV	5	250	202.0	201.0	28.0
SN74LVC1G06DBVTG4	SOT-23	DBV	5	250	180.0	180.0	18.0
SN74LVC1G06DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
SN74LVC1G06DCKT	SC70	DCK	5	250	205.0	200.0	33.0
SN74LVC1G06DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G06DRLR	SOT	DRL	5	4000	202.0	201.0	28.0
SN74LVC1G06DRLR	SOT	DRL	5	4000	184.0	184.0	19.0
SN74LVC1G06DRYR	SON	DRY	6	5000	184.0	184.0	19.0
SN74LVC1G06DSFR	SON	DSF	6	5000	184.0	184.0	19.0
SN74LVC1G06YZPR	DSBGA	YZP	5	3000	220.0	220.0	35.0
SN74LVC1G06YZVR	DSBGA	YZV	4	3000	220.0	220.0	35.0

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-178 Variation AA.



DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



DCK (R-PDSO-G5)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs.

 Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.
- D. JEDEC package registration is pending.



DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over—print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. SON (Small Outline No-Lead) package configuration.
- The exposed lead frame feature on side of package may or may not be present due to alternative lead frame designs.
- E. This package complies to JEDEC MO-287 variation UFAD.
- $frac{f}{K}$ See the additional figure in the Product Data Sheet for details regarding the pin 1 identifier shape.



DRY (R-PUSON-N6)

PLASTIC SMALL OUTLINE NO-LEAD



NOTES: A.

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over—print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.





- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Reference JEDEC registration MO-287, variation X2AAF.





PLASTIC SMALL OUTLINE NO-LEAD

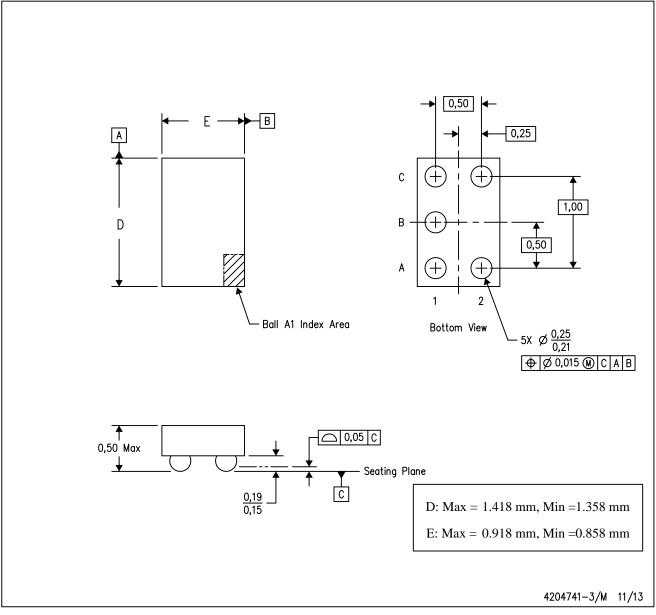


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads. If 2 mil solder mask is outside PCB vendor capability, it is advised to omit solder mask.
- E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Suggest stencils cut with lasers such as Fiber Laser that produce the greatest positional accuracy.
- H. Component placement force should be minimized to prevent excessive paste block deformation.



YZP (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree \mathbf{M} package configuration.

NanoFree is a trademark of Texas Instruments.



YZV (S-XBGA-N4)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.

- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.

NanoFree is a trademark of Texas Instruments.



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